

查询"BS500B"供应商

BS500B

Photodiode for Visible Light

T-41-51

■ Features

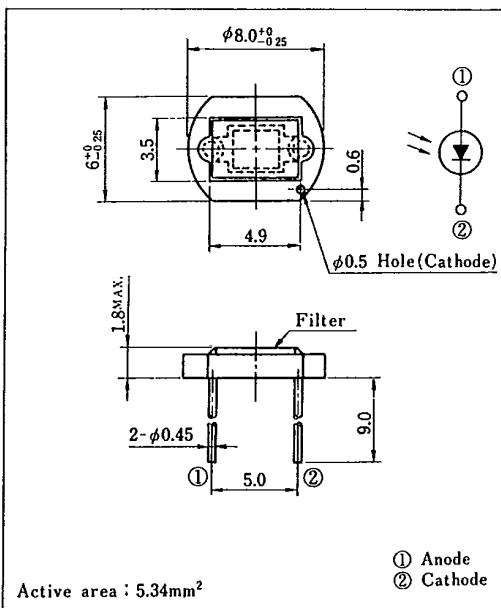
- Wide dynamic range (Capable of measuring 10^{-3} to 10^4 lx of E_v)
- Low dark current (I_d : MAX. 10^{-11} A at $V_R=1V$)
- Most suitable for visible light measurement ($\lambda_p=560nm$)
- Infrared light cut-off type

■ Applications

- AE (automatic exposure) system and ES (electronic shutter) system for cameras
- Stroboscopes
- Precise optical instruments

■ Outline Dimensions

(Unit : mm)

**■ Absolute Maximum Ratings**

(Ta=25°C)

Parameter	Symbol	Rating	Unit
Reverse voltage	V_R	10	V
Operating temperature	T_{opr}	-20 ~ +60	°C
Storage temperature	T_{stg}	-20 ~ +80	°C
*Soldering temperature	T_{sol}	260	°C

*1 For 5 seconds

■ Electro-optical Characteristics

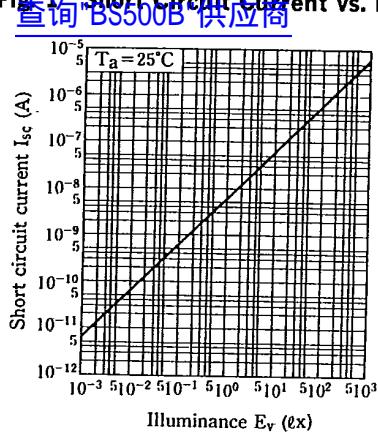
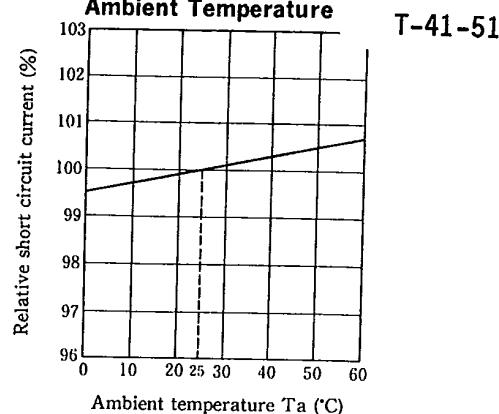
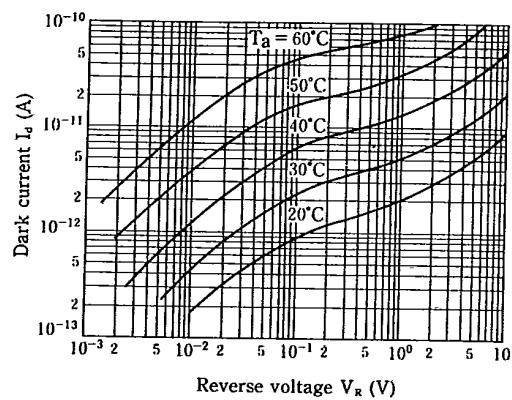
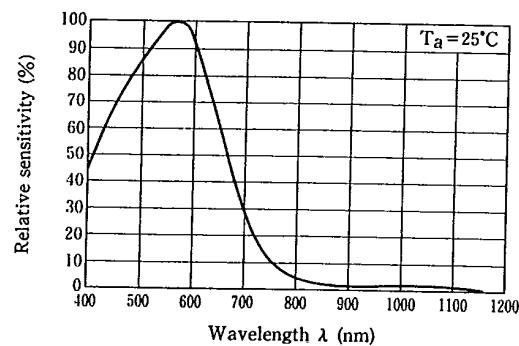
(Ta=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
* ² Short circuit current	I_{sc}	$E_v=100$ lx	0.40	0.55	0.65	μA
* ² Short circuit current temperature coefficient	β_T	$E_v=100$ lx	—	0.02	0.06	%/°C
Dark current	I_d	$V_R=1V$	—	3×10^{-12}	10^{-11}	A
Dark current temperature coefficient	α_T	$V_R=1V$	—	4.0	5.0	times/10°C
Terminal capacitance	C_t	$V_R=0, f=1MHz$	—	600	1,000	pF
Peak sensitivity wavelength	λ_p		500	560	600	nm
* ³ Spectral sensitivity infrared radiation ratio	ΔI_R		—	5	—	%

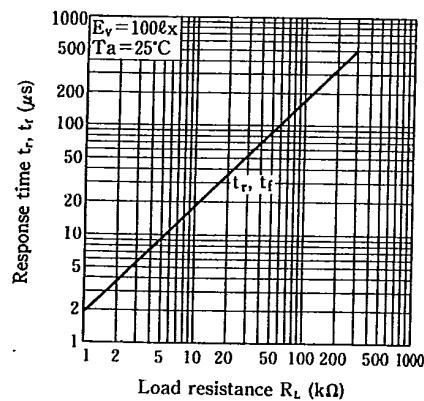
*2 E_v : Illuminance by CIE standard light source A (tungsten lamp)

$$*3 \Delta I_R = \frac{I_{sc} (\lambda \geq 700nm)}{I_{sc} (\text{full wavelength})} \times 100\%$$

SHARP

Fig. 1 Short Circuit Current vs. Illuminance**Fig. 2 Relative Short Circuit Current vs. Ambient Temperature****Fig. 3 Dark Current vs. Reverse Voltage****Fig. 4 Spectral Sensitivity**

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Fig. 5 Response Time vs. Load Resistance**Test Circuit for Response Time**